## NSN 5962-01-352-7922

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View Online at https://aerobasegroup.com/nsn/5962-01-352-7922

Body Length:
0.640 inches
Body Width:
Between 0.300 inches and 0.420 inches
Body Height:
Between 0.045 inches and 0.090 inches
Maximum Power Dissipation Rating:
1.04 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and hermetically sealed and burn in and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
F-6 mil-m-38510
Current Rating Per Characteristic:
190.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
15.00 input pascal industrial light tank stock and 12.00 output pascal industrial light tank stock
Time Rating Per Chacteristic:
40.00 nanoseconds access
Memory Device Type:
Prom
Special Features:
Nuclear hardness critical items
Nuclear Hardness Critical Feature:

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**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type Aı	nd Quantity:
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24 flat leads

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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